

● Features:

1. Current transfer ratio (CTR: MIN. 50% at $I_F=5\text{mA}$, $V_{CE}=5\text{V}$)
2. High input-output isolation voltage ($V_{ISO}=5,000\text{Vrms}$)
3. Response time (t_r : TYP. $4\mu\text{s}$ at $V_{CE}=2\text{V}$, $I_C=2\text{mA}$, $R_L=100\Omega$)
4. VDE approved(NO.40007240)
5. UL/CUL approved(NO.E236324)
6. CQC approved(NO.CQC08001026994
NO.CQC05001014257)
7. This product doesn't contain restriction substance, comply RoHS standard

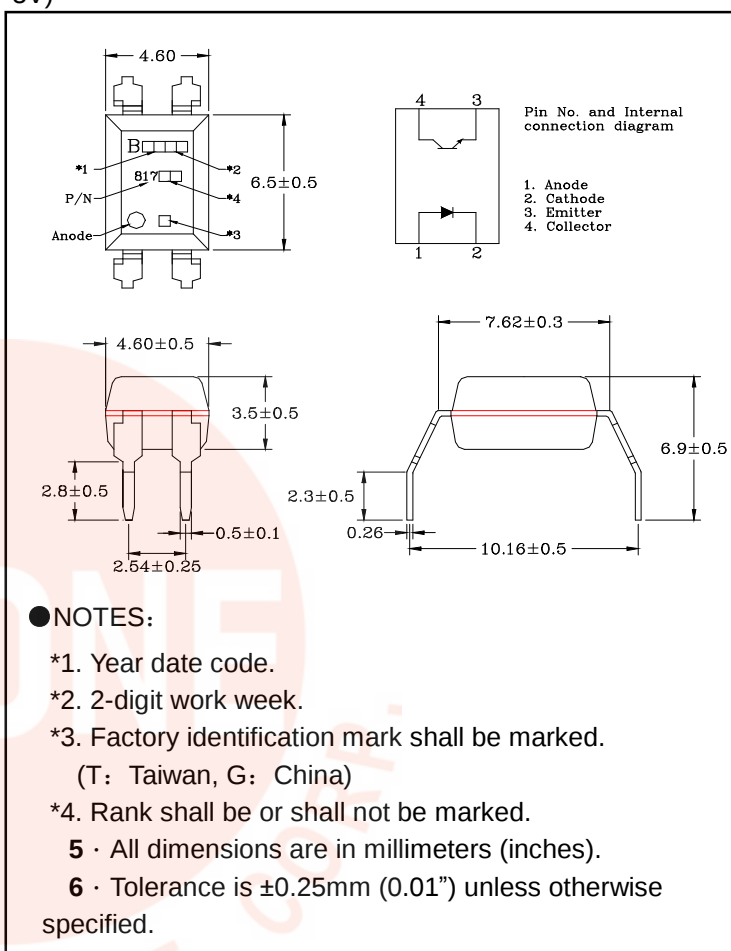
● Description

1. The BPC-817M series are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor
2. The lead pitch is 2.54mm

● Applications:

1. Computer terminals.
2. System appliances, measuring instruments.
3. Registers, copiers, automatic vending machines.
4. Electric home appliances, such as fan heaters, etc.
5. Signal transmission between circuits of different potentials and impedances.

● Outline Dimensions



● NOTES:

- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked.
(T: Taiwan, G: China)
- *4. Rank shall be or shall not be marked.
- 5 · All dimensions are in millimeters (inches).
- 6 · Tolerance is $\pm 0.25\text{mm}$ (0.01") unless otherwise specified.

● Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
INPUT	Forward Current	50	mA
	Reverse Voltage	6	V
	Power Dissipation	70	mW
OUTPUT	Collector-Emitter Voltage	80	V
	Emitter- Collector Voltage	6	
	Collector Current	50	mA
	Collector Power Dissipation	150	mW
Total Power Dissipation	P_{tot}	200	mW
*1 Isolation Voltage	V_{iso}	5,000	Vrms
Rated impulse isolation voltage	V_{IOTM}	6,000	V
Rated repetitive peak isolation voltage	V_{IORM}	630	V
Operating Temperature	T_{opr}	-30 to + 110	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to + 125	
*2 Soldering Temperature	T_{sol}	260	

*1. AC For 1 minute, R.H. =40~60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds



● Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
INPUT	Forward Voltage	V_F	$I_F=20\text{mA}$	---	1.2	1.4	V
	Reverse Current	I_R	$V_R=6\text{V}$	---	---	10	μA
	Terminal Capacitance	C_t	$V=0, f=1\text{KHz}$	---	30	250	pF
OUTPUT	Collector Dark Current	I_{CEO}	$V_{CE}=20\text{V}, I_F=0$	---	---	100	nA
	Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=0.1\text{mA}$ $I_F=0$	80	---	---	V
	Emitter-Collector Breakdown Voltage	BV_{ECO}	$I_E=10\mu\text{A}$ $I_F=0$	6	---	---	V
TRANSFER CHARACTERISTICS	Collector Current	I_c	$I_F=5\text{mA}$	2.5	---	30	mA
	*1 Current Transfer Ratio	CTR	$V_{CE}=5\text{V}$	50	---	600	%
	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_F=20\text{mA}$ $I_C=1\text{mA}$	---	0.1	0.2	V
	Isolation Resistance	R_{iso}	DC500V 40~60%R.H.	5×10^{10}	1×10^{11}	---	Ω
	Floating Capacitance	C_f	$V=0, f=1\text{MHz}$	---	0.6	1	pF
	Cut-Off Frequency	f_c	$V_{CE}=5\text{V}, I_C=2\text{mA}$ $R_L=100\Omega, -3\text{dB}$	---	80	---	kHz
	Response Time(Rise)	t_r	$V_{CE}=2\text{V}, I_C=2\text{mA}$	---	4	18	μs
	Response Time(Fall)	t_f	$R_L=100\Omega$	---	3	18	μs

*1 CTR= $I_C / I_F \times 100\%$

● RANK TABLE OF CURRENT TRANSFER RATIO(CTR)

RANK MARK.	Min. (%)	Max. (%)
L	50	100
A	80	160
B	130	260
C	200	400
D	300	600
L or A or B or C or D	50	600

Notes:

*1. Conditions: $I_F=5\text{mA}$, $V_{CE}=5\text{V}$, $T_a=25^\circ\text{C}$.

● CHARACTERISTICS CURVES

Fig.1 Forward Current
vs. Ambient Temperature

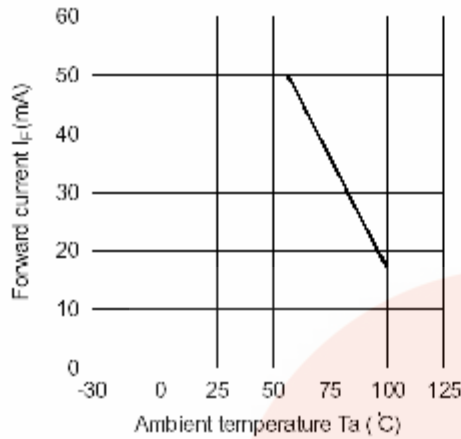


Fig.2 Collector Power Dissipation
vs. Ambient Temperature

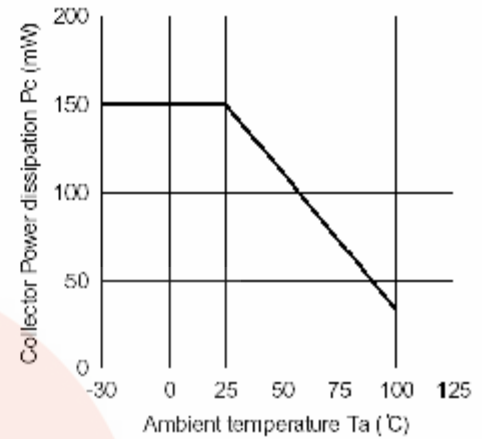


Fig.3 Collector-emitter Saturation
Voltage vs. Forward Current

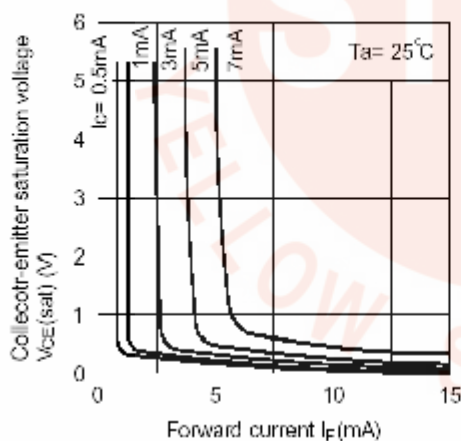


Fig.4 Forward Current vs. Forward
Voltage

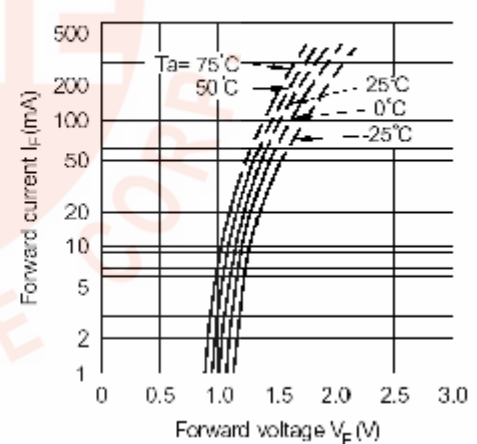


Fig.5 Current Transfer Ratio vs.
Forward Current

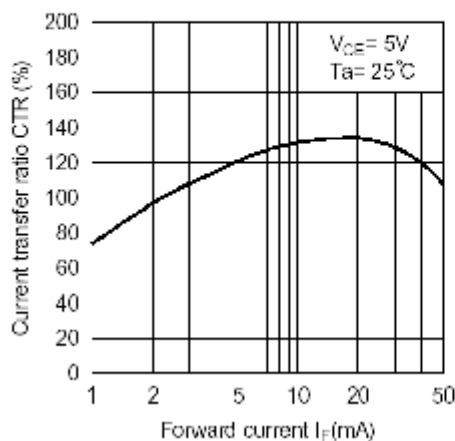
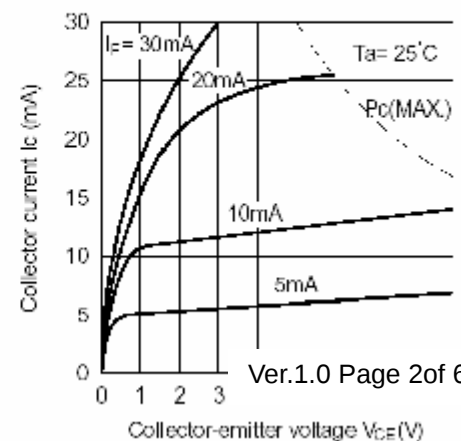


Fig.6 Collector Current vs.
Collector-emitter Voltage



● Characteristics Curves

Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

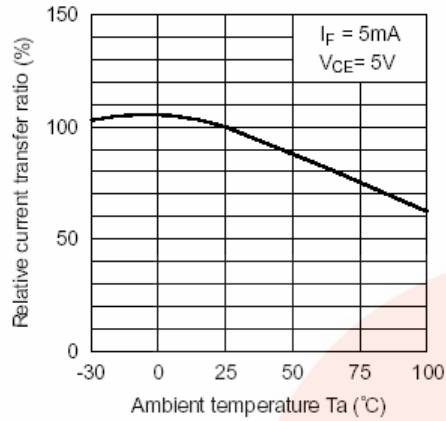


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

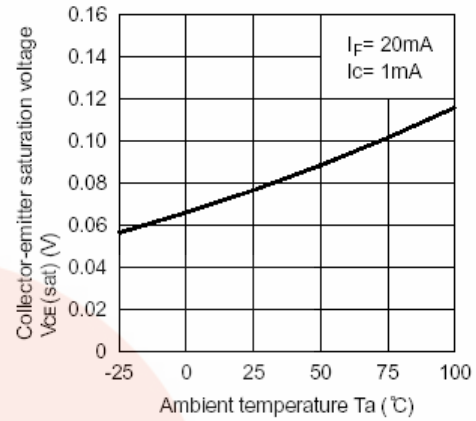


Fig.9 Collector Dark Current vs. Ambient Temperature

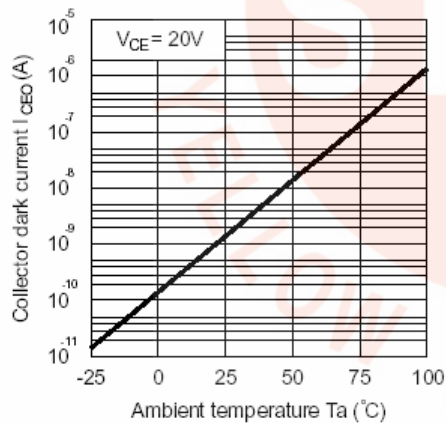


Fig.10 Response Time vs. Load Resistance

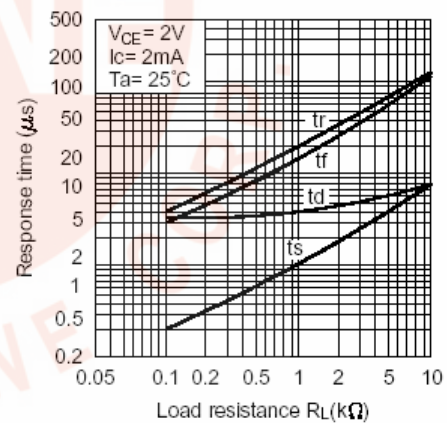
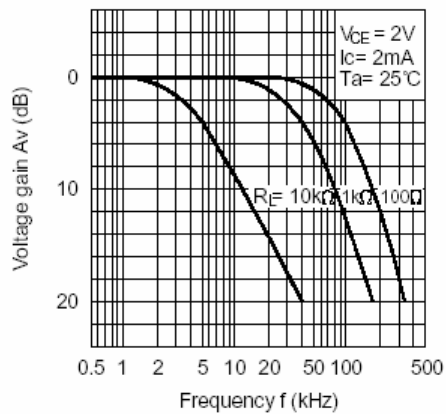
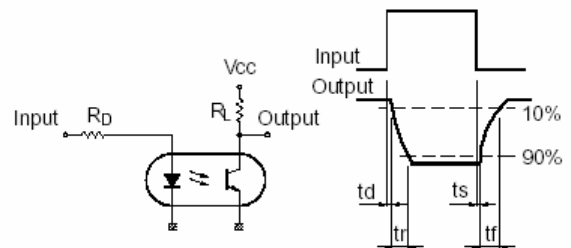


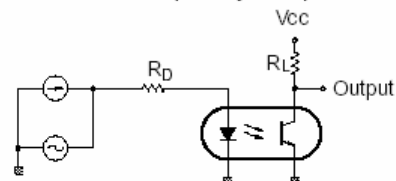
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response



● Reliability Test

Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power $I_f=50\text{mA}$ T_a =Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Reverse Bias (H3TRB)	JIS C 7021 :B-11	$T_a=+85^\circ\text{C}\pm 5^\circ\text{C}$, RH=85% $\text{PTR}=V_{\text{CE}}$ absolute max rating*80% Test time=1000hrs	0/20
	High Temperature Reverse Bias (HTRB)	JIS C 7021 :B- 8	$T_a=+105^\circ\text{C}\pm 5^\circ\text{C}$ $\text{PTR}=V_{\text{CE}}$ absolute max rating Test time=1000hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :B-10	High $T_a=+125^\circ\text{C}\pm 5^\circ\text{C}$ Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low $T_a=-55^\circ\text{C}\pm 5^\circ\text{C}$ Test time=1,000hrs	0/20
	Autoclave	JESD 22-A102-B	$P=15\text{PSIG}$, $T_a=121^\circ\text{C}$ Humi. =100%RH, 48hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	$125^\circ\text{C} \sim 25^\circ\text{C} \sim -55^\circ\text{C} \sim 25^\circ\text{C}$ 30min 5min 30min 5min Test Time=20cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	$125^\circ\text{C} \sim -55^\circ\text{C}$ 20min 20min Test Time=20cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Operation heating : 260°C , within $10\pm 1\text{seconds}$.	0/20
	Solder Ability	MIL-S-883:2003 JIS C 7021 :A-2	Operation heating : 235°C , within $5\pm 1\text{seconds}$.	0/20

● Judgment Criteria Of Failure For The Reliability

Symbol	Measuring conditions	Judgment criteria for failure
V_F (V)	$I_f=20\text{mA}$	Over $U_{x1.0}$
I_r (μA)	$V_r=6\text{V}$	Over $U_{x1.0}$
CTR(%)	$I_f=5\text{mA}$, $V_{\text{CE}}=5\text{V}$	Shift>1.2
$V_{\text{CE(sat)}}$	$I_F=20\text{mA}$, $I_C=1\text{mA}$	Over $U_{x1.0}$
BV_{CEO}	$I_C=0.1\text{mA}$, $I_F=0$	Over $L_{x1.0}$
BV_{ECO}	$I_E=10\mu\text{A}$, $I_F=0$	Over $L_{x1.0}$